

Power Matters.™

[Home](#) ▶ [2N0918 \(#19737\)](#)

Products

- ▶ [Product Directory](#)
- ▶ [Applications](#)
- ▶ [Parametric Search](#)

2N0918 (#19737)

Product Status

■ Obsolete

Related Links

[Technical support](#)
[How to Buy](#)
[Available Stock](#)
[Sales Contacts](#)

Overview

Diagrams

Electrical Rating	Symbol	Min	Typ	Max	Unit
Bandwidth	BW	600.00			MHz
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$			0.40	V
DC Current Gain	HFE	20.00		200.00	

Maximum Electrical Rating	Symbol	Min	Typ	Max	Unit
Breakdown Voltage, Collector-Base (Emitter Open)	$V_{BR(CBO)}$			30.00	V
Collector Current (dc)	I_C			0.05	A
Collector-Emitter Voltage (Base Open)	V_{CEO}			15.00	V
Emitter-Base Voltage (Collector Open)	V_{EBO}			3.00	V
Power Dissipation, Total	P_T			0.20	W

This part can be found in the following product categories:

▶ [Power Discretes & Modules](#) ▶ [BJT \(BiPolar Junction Transistor\)](#) ▶ [PNP Transistor](#)